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### HMC587\* Product Page Quick Links

Last Content Update: 08/30/2016

### Comparable Parts

View a parametric search of comparable parts

### Evaluation Kits

• HMC587LC4B Evaluation Board.

### Documentation 🖵

### **Data Sheet**

• HMC587 Data Sheet

### Reference Materials

### **Quality Documentation**

- Package/Assembly Qualification Test Report: LC4, LC4B (QTR: 2014-00380 REV: 01)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

### **Technical Articles**

• SMT Wideband MMIC VCOs Tune from 4 to 12.5 GHz

### Design Resources 🖵

- HMC587 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

### Discussions 🖵

View all HMC587 EngineerZone Discussions

### Sample and Buy

Visit the product page to see pricing options

### Technical Support

Submit a technical question or find your regional support number

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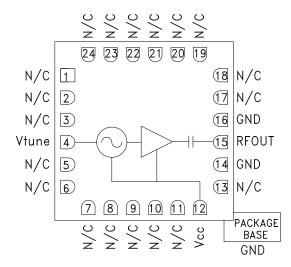


### **Typical Applications**

Low noise wideband MMIC VCO for applications such as:

- Industrial/Medical Equipment
- Test & Measurement Equipment
- Military Radar, EW & ECM

### **Functional Diagram**



### WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 5 - 10 GHz

HMC587LC4B

### Features

Wide Tuning Bandwidth Pout: +5 dBm Low SSB Phase Noise: -95 dBc/Hz @100 kHz No External Resonator Needed Single Positive Supply: +5V @ 55 mA RoHS Compliant 4 x 4 mm SMT Package

### **General Description**

The HMC587LC4B is a wideband GaAs InGaP Voltage Controlled Oscillator which incorporates the resonator, negative resistance device, and varactor diode. Output power and phase noise performance are excellent over temperature due to the oscillator's monolithic construction. The Vtune port accepts an analog tuning voltage from 0 to +18 volts. The HMC587LC4B VCO operates from a single +5V supply, consumes only 55 mA of current, and is housed in a RoHS compliant SMT package. This wideband VCO uniquely combines the attributes of ultra small size, low phase noise, low power consumption, and wide tuning range.

### Electrical Specifications, $T_{A} = +25^{\circ} C$ , Vcc = +5V

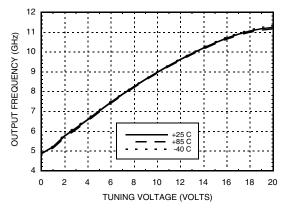
Parameter	Min.	Тур.	Max.	Units
Frequency Range	iency Range 5.0 - 10.0			GHz
Power Output	0	5		dBm
SSB Phase Noise @ 100 kHz Offset		-95		dBc/Hz
SSB Phase Noise @ 10 kHz Offset		-65		dBc/Hz
Tune Voltage (Vtune)	0		18	V
Supply Current (Icc) (Vcc = +5.0V)	40		75	mA
Tune Port Leakage Current (Vtune = +18V)			10	μA
Output Return Loss		7		dB
2nd Harmonic		-15		dBc
Pulling (into a 2.0:1 VSWR)		4		MHz pp
Pushing @ Vtune= +5V		15		MHz/V
Frequency Drift Rate		0.8		MHz/°C

For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com Application Support: Phone: 978-250-3343 or apps@hittite.com

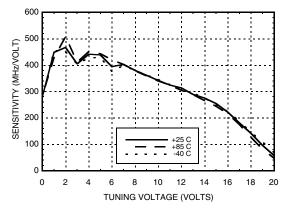




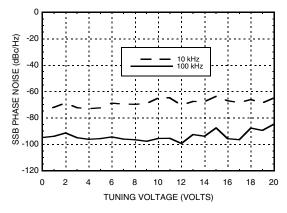
### Frequency vs. Tuning Voltage, Vcc = +5V



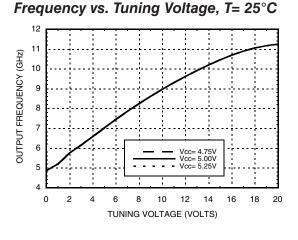
Sensitivity vs. Tuning Voltage, Vcc= +5V



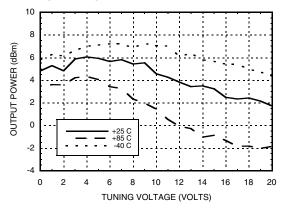
SSB Phase Noise vs. Tuning Voltage



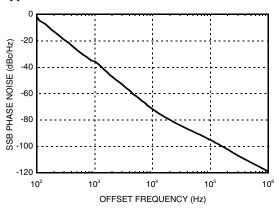
### WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 5 - 10 GHz



### Output Power vs. Tuning Voltage, Vcc= +5V



### Typical SSB Phase Noise @ Vtune= +5V



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### WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 5 - 10 GHz

### Absolute Maximum Ratings

**Outline Drawing** 

Vcc	+5.5 Vdc
Vtune	0 to +22V
Junction Temperature	135 °C
Continuous Pdiss (T = 85°C) (derate 12.5 mW/°C above 85°C)	625 mW
Thermal Resistance (junction to ground paddle)	80 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



# WIDEBAND VCOS - SMT

PIN 24 0.157±0.005 .014 0.36 .009 0.24 .013 [0.32] [4.00±0.13] REF 19 24 PIN 1 PIN 1 18 D 1 0.157±0.005 [4.00±0.13] D H587 D de 0.56 .022 .017  $\mathsf{D}$ X X X X.101 D 13 Л 6  $\square$   $\square$   $\square$   $\square$   $\square$   $\square$   $\square$ 12 EXPOSED .098 [2.50] LOT NUMBER GROUND SQUARE PADDLE -.122 [3.10]-.047 [1.20] MAX SEATING NOTES: PLANE 1. PACKAGE BODY MATERIAL: ALUMINA 2. LEAD AND GROUND PADDLE PLATING: GOLD FLASH OVER Ni. -C-3. DIMENSIONS ARE IN INCHES [MILLIMETERS].

BOTTOM VIEW

4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE

5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-

6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC587LC4B	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H587 XXXX

[1] Max peak reflow temperature of 260 °C [2] 4-Digit lot number XXXX

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### WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 5 - 10 GHz

### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1 - 3, 5 - 11, 13, 17 - 24	N/C	No Connection. These pins may be connected to RF/DC ground. Performance will not be affected.	
4	Vtune	Control Voltage and Modulation Input. Modulation bandwidth dependent on drive source impedance. See "Determining the FM Bandwidth of a Wideband Varactor Tuned VCO" application note.	Vtune ○ 750∩ 2.4pF 3.0pF
12	Vcc	Supply Voltage Vcc= +5V	Vcc O
14, 16	GND	Package bottom has an exposed metal paddle that must also be RF & DC grounded.	
15	RFOUT	RF output (AC coupled)	

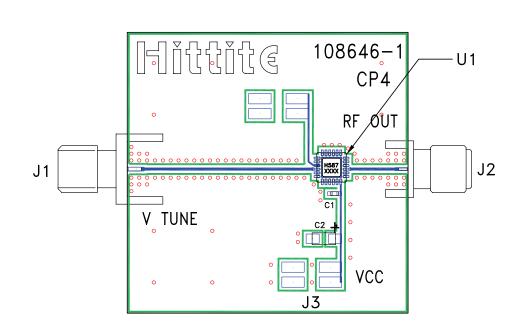




### WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 5 - 10 GHz

# ROHS

### **Evaluation PCB**



### List of Materials for Evaluation PCB 108648 [1]

Item	Description
J1	PCB Mount SMA RF Connector, Johnson
J2	PCB Mount SMA Connector, SRI
J3	DC Header
C1	1000 pF Capacitor, 0402 Pkg.
C2	4.7 µF Capacitor, Tantalum
U1	HMC587LC4B VCO
PCB [2]	108646 Eval Board

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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